

PRELIMINARY SPEC

BA56-11SEWA

SUPER BRIGHT ORANGE

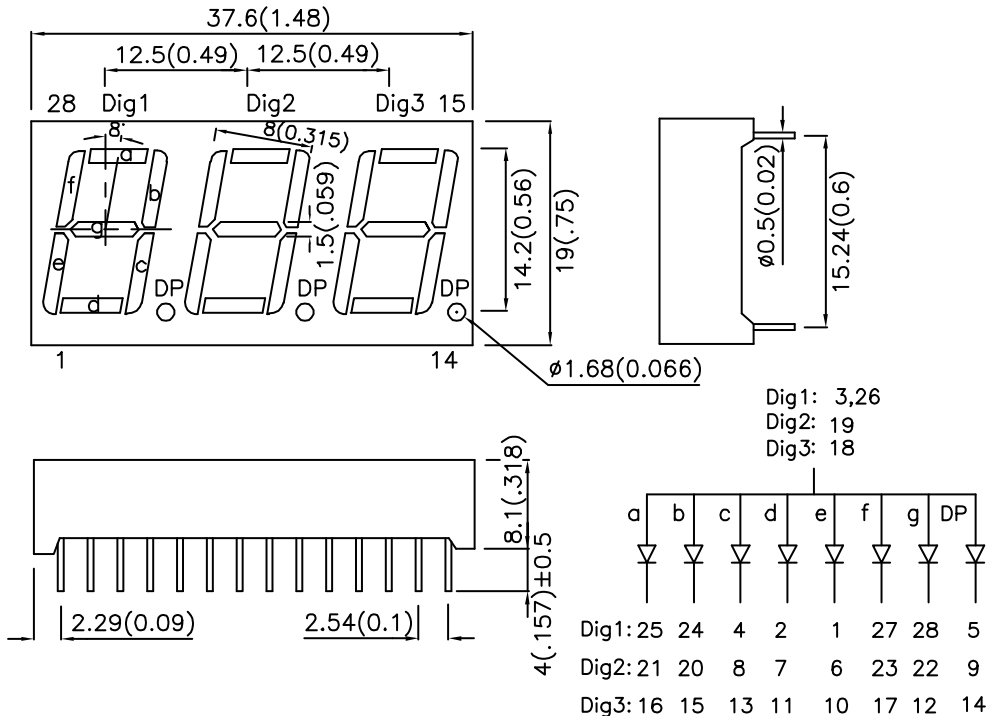
Features

- 0.56 INCH DIGIT HEIGHT.
- LOW CURRENT OPERATION.
- EXCELLENT CHARACTER APPEARANCE.
- EASY MOUNTING ON P.C. BOARDS OR SOCKETS.
- I.C. COMPATIBLE.
- MECHANICALLY RUGGED.
- STANDARD: GRAY FACE, WHITE SEGMENT.

Description

The Super Bright Orange source color devices are made with DH InGaAlP on GaAs substrate Light Emitting Diode.

Package Dimensions & Internal Circuit Diagram



Notes:

1. All dimensions are in millimeters (inches), Tolerance is $\pm 0.25 (0.01)$ unless otherwise noted.
2. Specifications are subject to change without notice.

Selection Guide

Part No.	Dice	Lens Type	Iv (ucd) @ 10mA		Description
			Min.	Typ.	
BA56-11SEWA	SUPER RIGHT ORANGE (InGaAlP)	WHITE DIFFUSED	26000	116536	Common Anode ,Rt. Hand Decimal.

Electrical / Optical Characteristics at TA=25°C

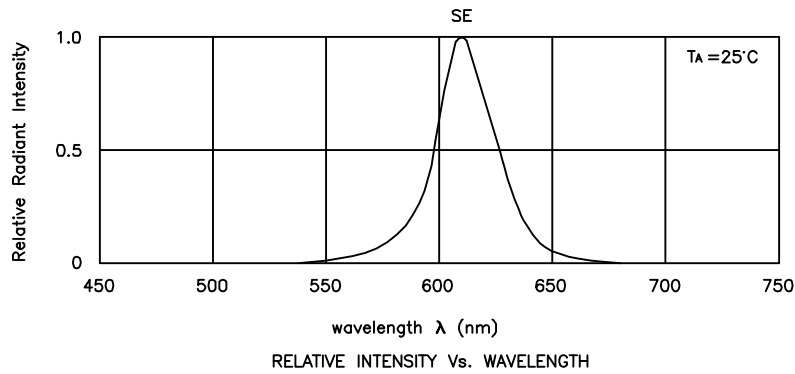
Symbol	Parameter	Device	Typ.	Max.	Units	Test Conditions
λ_{peak}	Peak Wavelength	Super Bright Orange	610		nm	IF=20mA
λ_D	Dominate Wavelength	Super Bright Orange	601		nm	IF=20mA
$\Delta\lambda_{1/2}$	Spectral Line Half-width	Super Bright Orange	29		nm	IF=20mA
C	Capacitance	Super Bright Orange	30		pF	VF=0V;f=1MHz
VF	Forward Voltage	Super Bright Orange	2.0	2.5	V	IF=20mA
IR	Reverse Current	Super Bright Orange		10	uA	VR= 5V

Absolute Maximum Ratings at TA=25°C

Parameter	Super Bright Orange	Units
Power dissipation	75	mW
DC Forward Current	30	mA
Peak Forward Current [1]	195	mA
Reverse Voltage	5	V
Operating / Storage Temperature	-40°C To +85°C	
Lead Solder Temperature [2]	260°C For 3 Seconds	

Notes:

- 1/10 Duty Cycle, 0.1ms Pulse Width.
- 2mm below package base.



Super Bright Orange

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